## NSN 5962-01-165-3112

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View Online at https://aerobasegroup.com/nsn/5962-01-165-3112 **Body Length:** 0.890 inches **Body Width:** 0.220 inches **Body Height:** 0.125 inches **Maximum Power Dissipation Rating:** 375.0 milliwatts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Test set 9900a **Features Provided:** Hermetically sealed and 3-state output and low power and programmable **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** Yes - demil/mli

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